

Semiconductor Device Processing

Electrical and Computer Engineering Department
University of California, Santa Barbara

In this class, we will cover the fundamentals of semiconductor processing. The class meets two days per week and is supplemented by lab projects, which are performed in the UCSB instructional cleanroom in Engineering II. In the classroom, we will study a number of techniques used in the processing of semiconductor devices. In the lab, you will get to experiment with the techniques discussed in class. You will also fabricate and test an NMOS transistor.

Topics to be covered

- Optical Lithography
- Thermal Oxidation
- Junction Formation
 - Diffusion
 - Ion Implantation
- Etching
 - Wet Etching
 - Reactive Ion Etching
- Thin Film Deposition
 - Evaporation
 - Sputtering
 - Chemical Vapor Deposition
- Ohmic Contact Formation
- NMOS Process and Characterization

Instructor: Ilan Ben-Yaacov, HFH Room 5111, ext. 5295, ilan@ece.ucsb.edu

Class Time: Monday and Wednesday 9:30 – 10:45am

Place: GIRV 2112

Required Text: *Fundamentals of Semiconductor Fabrication* by G. S. May and S. M. Sze, published by John Wiley and Sons, 2004, ISBN 0-471-45238-6.

Other texts you may find useful:

Fabrication Engineering at the Micro- and Nanoscale (3rd edition), by Stephen A. Campbell, published by Oxford, 2008.

Silicon Processing for the VLSI Era, Volume 1 - Process Technology by S. Wolf and R. N. Tauber, published by Lattice Press, 2000.

Handouts and class notes will complement the text. All handouts, including this syllabus, can be downloaded from the class web page: http://www.ece.ucsb.edu/courses/ECE120/120A_W20Ilan/

Prerequisite: ECE 132 with a grade of C- or better, or equivalent, or consent of instructor.

Course Format: There will be homework assignments, a midterm, laboratory work, and a final lab project. Laboratory work will consist of experimenting with various processes such as lithography, thermal oxidation, and wet etching, and determining process tolerances. For the final project, you will use the skills you have developed in the lab to fabricate and characterize a MOS transistor. Homework, midterm, lab, and final lab project will each contribute 15%, 30%, 15%, and 40% to the final grade.

Office Hours: Instructor office hours are Mon/Wed 11:00–11:50am in HFH Room 5111. TA lab hours TBA.

Laboratory Hours: There are no scheduled hours for the lab work. The instructional cleanroom will be available M-F 8am-5pm with key card access, if two or more students are working together. For safety reasons, you will not be permitted to work alone. There will be equipment demonstration sessions, which are required. TA lab hours will be posted, it is always best to work in the lab during times that a TA is present.

Lab Safety: It is essential that safety procedures be followed at all times. You will be working with acids (including HF), bases, and organic solvents that can be hazardous if not handled properly. You are required to attend a safety orientation session before you will be permitted to enter the lab. There are sessions provided by the university, and a series of tapes provided by the ECE department and Bob Hill.

Lab Supervisor: Bob Hill, Room 1141, Engineering II, ext. 4142, bob@ece.ucsb.edu

Teaching Assistants: Pari Patel (ppatel01@umail.ucsb.edu), lab hours TBA.
Kevin Conner (kevinconner@umail.ucsb.edu), lab hours TBA.

Class Web Page: http://www.ece.ucsb.edu/courses/ECE120/120A_W201lan/